



ST13007N ST13007NFP

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTORS

- HIGH VOLTAGE CAPABILITY
- NPN TRANSISTOR
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED

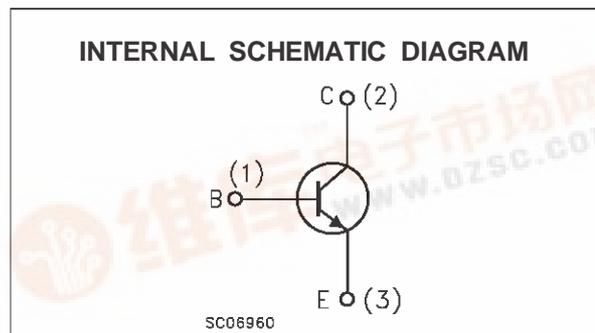
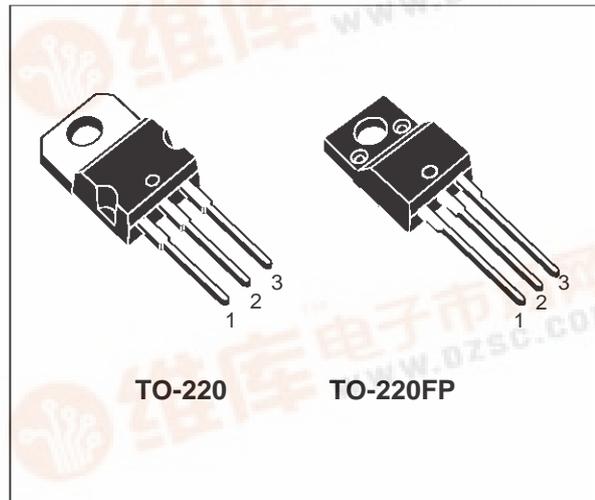
APPLICATIONS

- ELECTRONIC BALLASTS FOR FLUORESCENT LIGHTING
- SWITCH MODE POWER SUPPLIES

DESCRIPTION

The device is manufactured using high voltage Multi Epitaxial Planar technology for high switching speeds and high voltage capability.

They use a Cellular Emitter structure to enhance switching speeds.



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | | Unit |
|-----------|--|------------|------------|------------|
| | | ST13007N | ST13007NFP | |
| V_{CEV} | Collector-Emitter Voltage ($V_{BE} = -1.5V$) | 700 | | V |
| V_{CEO} | Collector-Emitter Voltage ($I_B = 0$) | 400 | | V |
| V_{EBO} | Emitter-Base Voltage ($I_C = 0$) | 9 | | V |
| I_C | Collector Current | 8 | | A |
| I_{CM} | Collector Peak Current | 16 | | A |
| I_B | Base Current | 4 | | A |
| I_{BM} | Base Peak Current | 8 | | A |
| P_{tot} | Total Dissipation at $T_c \leq 25^\circ C$ | 80 | 33 | W |
| T_{stg} | Storage Temperature | -65 to 150 | | $^\circ C$ |
| T_j | Max. Operating Junction Temperature | 150 | | $^\circ C$ |

ST13007N / ST13007NFP

THERMAL DATA

| | | | TO-220 | TO-220FP | |
|-----------------------|-------------------------------------|-----|--------|----------|------|
| R _{thj-case} | Thermal Resistance Junction-case | Max | 1.56 | 3.8 | °C/W |
| R _{thj-amb} | Thermal Resistance Junction-Ambient | Max | 62.5 | 62.5 | °C/W |

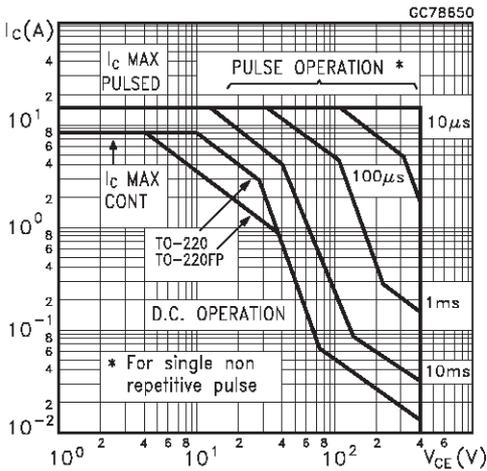
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|----------------------------------|---|--|---------------|-----------|-------------------|------------------|
| I _{CEV} | Collector Cut-off Current (V _{BE} = -1.5V) | V _{CE} = rated V _{CEV} V _{CE} = rated V _{CEV} T _c = 100 °C | | | 1 5 | mA mA |
| I _{EBO} | Emitter Cut-off Current (I _C = 0) | V _{EB} = 9 V | | | 1 | mA |
| V _{CEO(sus)*} | Collector-Emitter Sustaining Voltage | I _C = 10 mA | 400 | | | V |
| V _{CE(sat)*} | Collector-Emitter Saturation Voltage | I _C = 2 A I _B = 0.4 A I _C = 5 A I _B = 1 A I _C = 8 A I _B = 2 A I _C = 5 A I _B = 1 A T _c = 100 °C | | | 1 2 3 3 | V V V V |
| V _{BE(sat)*} | Base-Emitter Saturation Voltage | I _C = 2 A I _B = 0.4 A I _C = 5 A I _B = 1 A I _C = 5 A I _B = 1 A T _c = 100 °C | | | 1.2 1.6 1.5 | V V V |
| h _{FE*} | DC Current Gain | I _C = 2 A V _{CE} = 5 V Group A Group B I _C = 5 A V _{CE} = 5 V | 15 26 5 | | 28 40 30 | |
| t _s t _f | INDUCTIVE LOAD Storage Time Fall Time | I _C = 5 A V _{CL} = 200 V I _{B1} = 1 A V _{BEoff} = -5 V R _{BB} = 0 Ω | | 0.6 60 | 1.5 110 | μs ns |

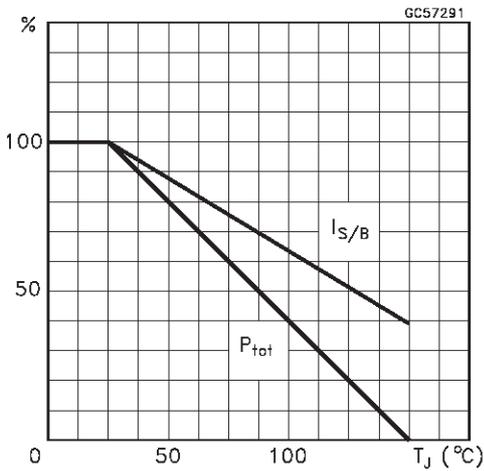
* Pulsed: Pulse duration = 300 μs, duty cycle 2 %

Note : Product is pre-selected in DC current gain (GROUP A and GROUP B). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

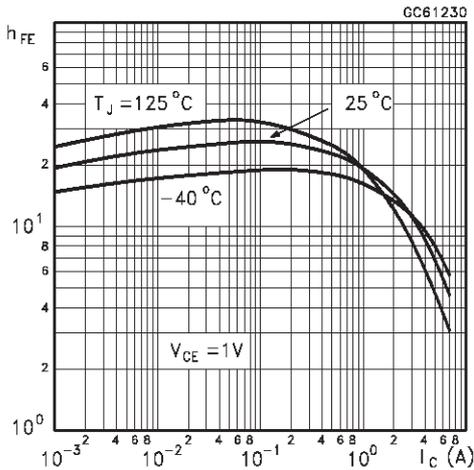
Safe Operating Areas



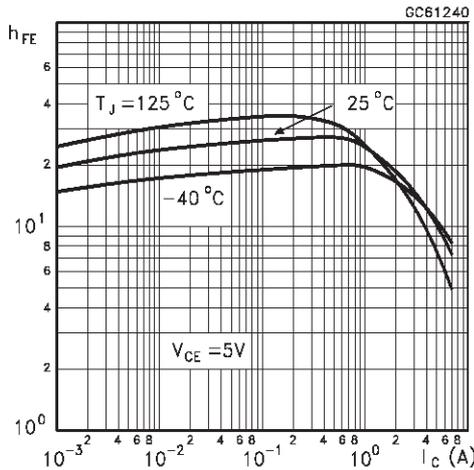
Derating Curve



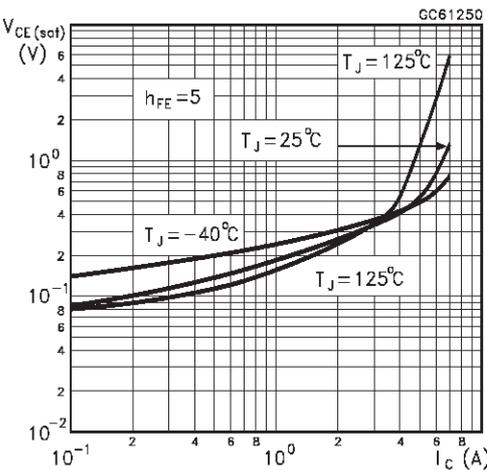
DC Current Gain



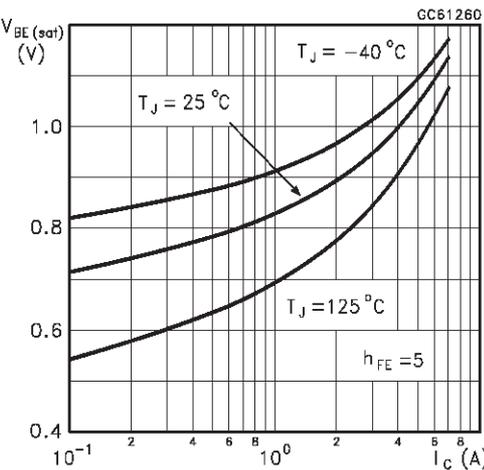
DC Current Gain



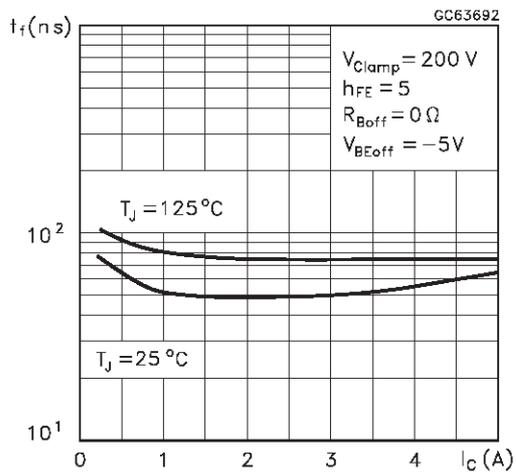
Collector Emitter Saturation Voltage



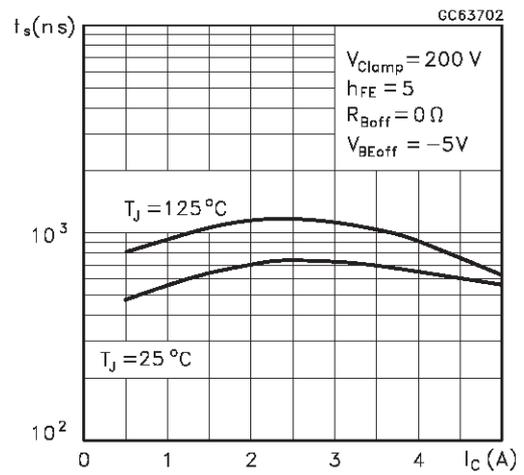
Base Emitter Saturation Voltage



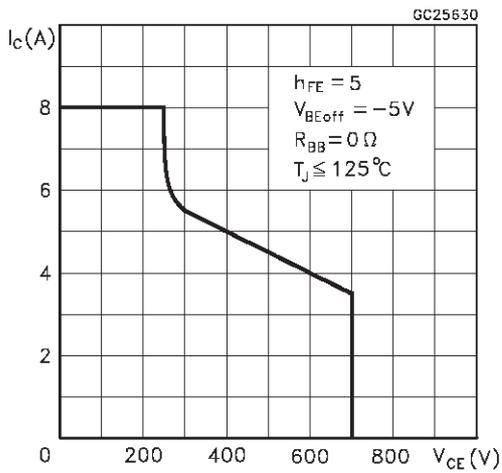
Inductive Fall Time



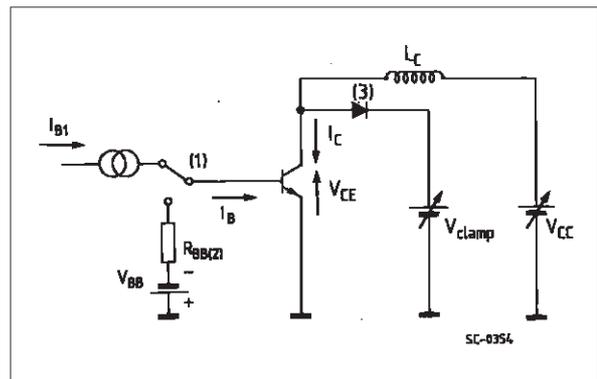
Inductive Storage Time



Reverse Biased SOA



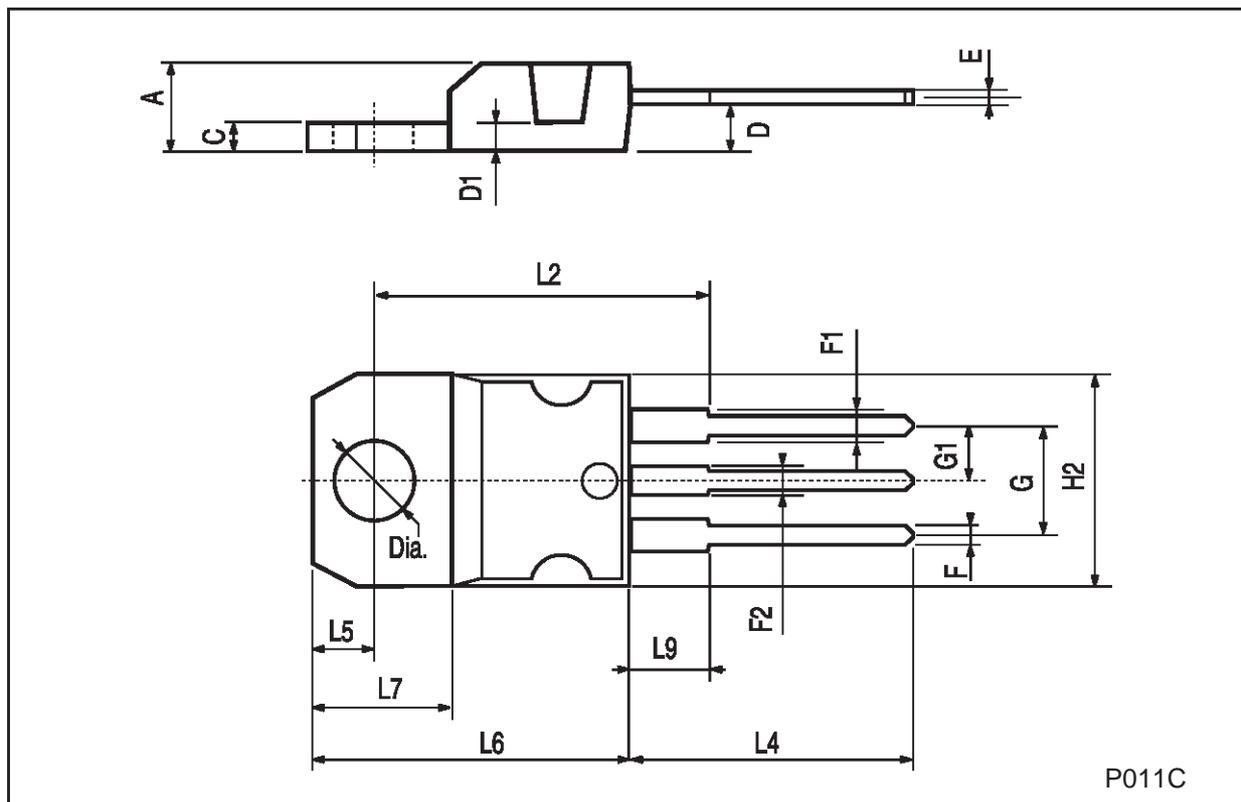
RBSOA and Inductive Load Switching Test Circuits



- 1) Fast electronic switch
- 2) Non-inductive Resistor
- 3) Fast recovery rectifier

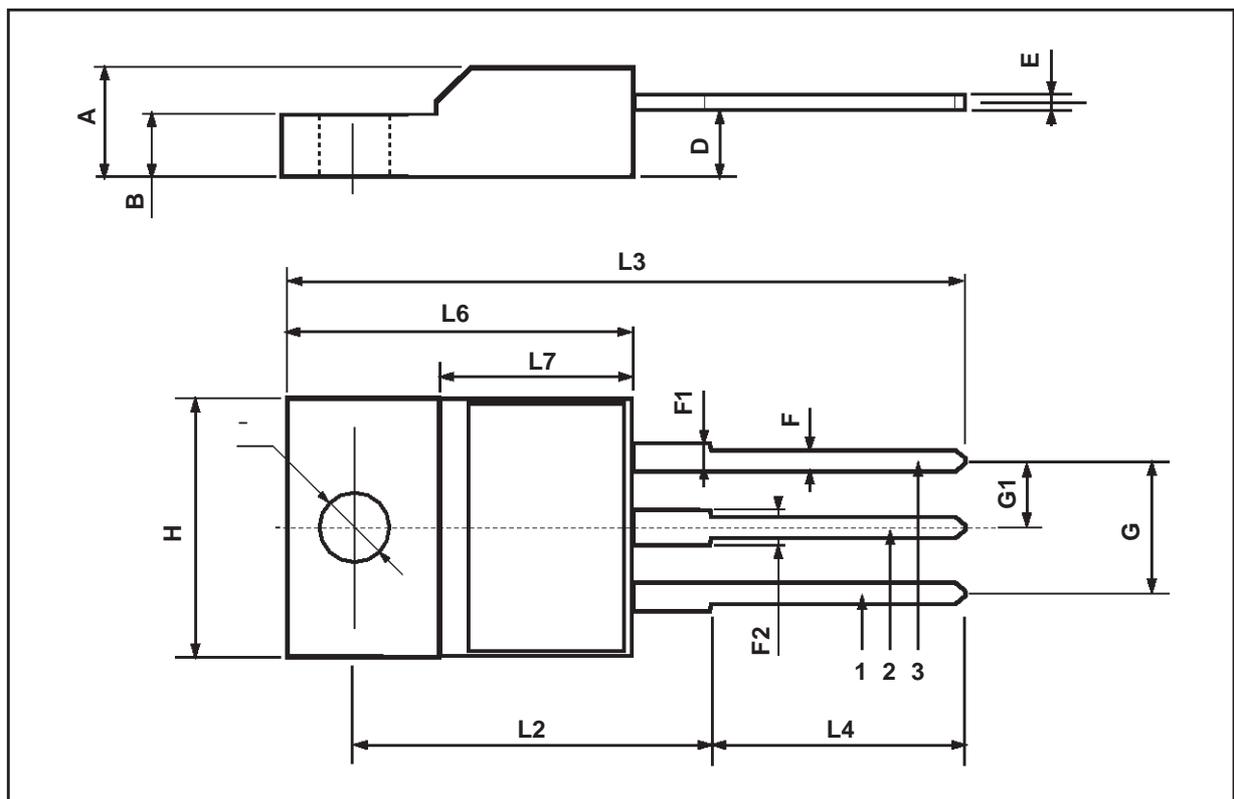
TO-220 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|-------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| C | 1.23 | | 1.32 | 0.048 | | 0.051 |
| D | 2.40 | | 2.72 | 0.094 | | 0.107 |
| D1 | | 1.27 | | | 0.050 | |
| E | 0.49 | | 0.70 | 0.019 | | 0.027 |
| F | 0.61 | | 0.88 | 0.024 | | 0.034 |
| F1 | 1.14 | | 1.70 | 0.044 | | 0.067 |
| F2 | 1.14 | | 1.70 | 0.044 | | 0.067 |
| G | 4.95 | | 5.15 | 0.194 | | 0.203 |
| G1 | 2.4 | | 2.7 | 0.094 | | 0.106 |
| H2 | 10.0 | | 10.40 | 0.393 | | 0.409 |
| L2 | | 16.4 | | | 0.645 | |
| L4 | 13.0 | | 14.0 | 0.511 | | 0.551 |
| L5 | 2.65 | | 2.95 | 0.104 | | 0.116 |
| L6 | 15.25 | | 15.75 | 0.600 | | 0.620 |
| L7 | 6.2 | | 6.6 | 0.244 | | 0.260 |
| L9 | 3.5 | | 3.93 | 0.137 | | 0.154 |
| DIA. | 3.75 | | 3.85 | 0.147 | | 0.151 |



TO-220FP MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.4 | | 4.6 | 0.173 | | 0.181 |
| B | 2.5 | | 2.7 | 0.098 | | 0.106 |
| D | 2.5 | | 2.75 | 0.098 | | 0.108 |
| E | 0.45 | | 0.7 | 0.017 | | 0.027 |
| F | 0.75 | | 1 | 0.030 | | 0.039 |
| F1 | 1.15 | | 1.7 | 0.045 | | 0.067 |
| F2 | 1.15 | | 1.7 | 0.045 | | 0.067 |
| G | 4.95 | | 5.2 | 0.195 | | 0.204 |
| G1 | 2.4 | | 2.7 | 0.094 | | 0.106 |
| H | 10 | | 10.4 | 0.393 | | 0.409 |
| L2 | | 16 | | | 0.630 | |
| L3 | 28.6 | | 30.6 | 1.126 | | 1.204 |
| L4 | 9.8 | | 10.6 | 0.385 | | 0.417 |
| L6 | 15.9 | | 16.4 | 0.626 | | 0.645 |
| L7 | 9 | | 9.3 | 0.354 | | 0.366 |
| ∅ | 3 | | 3.2 | 0.118 | | 0.126 |



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